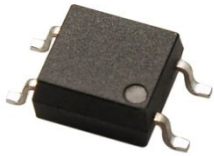
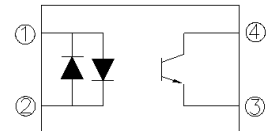


### 4 PIN SOP PHOTOTRANSISTOR PHOTOCOUPLER AC INPUT PHOTOCOUPLE EL354N-G Series



Schematic



Pin Configuration

1. Anode / Cathode
2. Cathode / Anode
3. Emitter
4. Collector

#### Features:

- Halogens free  
(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- Current transfer ratio  
(CTR: Min. 20% at  $I_F = \pm 1\text{mA}$  ,  $V_{CE} = 5\text{V}$ )
- High isolation voltage between input and output ( $V_{iso} = 3750\text{ V rms}$ )
- Compact small outline package
- Compliance with EU REACH
- Pb free and RoHS compliant
- UL and cUL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

#### Description

The EL354N-G series of devices each consist of two infrared emitting diode, connected in inverse parallel, optically coupled to a phototransistor detector.

They are packaged in a 4-pin small outline package.

#### Applications

- AC line monitor
- Programmable controllers
- Telephone line interface
- Unknown polarity DC sensor

**Absolute Maximum Ratings (Ta=25 )**

|                         | Parameter  | Symbol           | Rating     | Unit        |
|-------------------------|--|------------------|------------|-------------|
| Input                   | Forward current  | I <sub>F</sub>   | ±50        | mA          |
|                         | Peak forward current (1us, pulse)                                  | I <sub>FP</sub>  | 1          | A           |
|                         | Power dissipation<br>Derating factor (above T <sub>a</sub> = 90°C) | P <sub>D</sub>   | 70         | mW          |
| Output                  | Power dissipation<br>Derating factor (above T <sub>a</sub> = 70°C) | P <sub>C</sub>   | 150<br>3.7 | mW<br>mW/°C |
|                         | Collector-Emitter voltage  | V <sub>CEO</sub> | 80         | V           |
|                         | Emitter-Collector voltage  | V <sub>ECO</sub> | 6          | V           |
| Total Power Dissipation |  | P <sub>TOT</sub> | 200        | mW          |
| Isolation Voltage*1     |  | V <sub>ISO</sub> | 3750       | Vrms        |
| Operating temperature   |  | T <sub>OPR</sub> | -55 ~ +100 |             |
| Storage temperature     |  | T <sub>STG</sub> | -55 ~ +125 |             |
| Soldering Temperature*2 |  | T <sub>SOL</sub> | 260        |             |

Notes:

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

\*2 For 10 seconds

**Electro-Optical Characteristics (Ta=25 unless specified otherwise)**

**Input**

| Parameter         | Symbol   | Min. | Typ. | Max. | Unit | Condition                |
|-------------------|----------|------|------|------|------|--------------------------|
| Forward voltage   | $V_F$    | -    | 1.2  | 1.4  | V    | $I_F = \pm 20\text{mA}$  |
| Input capacitance | $C_{in}$ | -    | 50   | 250  | pF   | $V = 0, f = 1\text{KHz}$ |

**Output**

| Parameter                           | Symbol     | Min | Typ. | Max. | Unit | Condition                               |
|-------------------------------------|------------|-----|------|------|------|---|
| Collector-Emitter dark current      | $I_{CEO}$  | -   | -    | 100  | nA   | $V_{CE} = 20\text{V}, I_F = 0\text{mA}$ |
| Collector-Emitter breakdown voltage | $BV_{CEO}$ | 80  | -    | -    | V    | $I_C = 0.1\text{mA}$                    |
| Emitter-Collector breakdown voltage | $BV_{ECO}$ | 7   | -    | -    | V    | $I_E = 0.1\text{mA}$                    |

**Transfer Characteristics (Ta=25°C unless specified otherwise)**

| Parameter                            | Symbol                   | Min                | Typ.      | Max.       | Unit          | Condition  |
|--------------------------------------|--------------------------|--------------------|-----------|------------|---------------|--|
| Current Transfer ratio               | EL354N<br>EL354NA<br>CTR | 20<br>50           | -<br>-    | 300<br>150 | %             | $I_F = \pm 1\text{mA}, V_{CE} = 5\text{V}$                           |
| Collector-Emitter saturation voltage | $V_{CE(sat)}$            | -                  | 0.1       | 0.2        | V             | $I_F = \pm 20\text{mA}, I_C = 1\text{mA}$                            |
| Isolation resistance                 | $R_{IO}$                 | $5 \times 10^{10}$ | $10^{11}$ | -          | $\Omega$      | $V_{IO} = 500\text{Vdc}, 40\sim 60\% \text{R.H}$                     |
| Cut-off frequency                    | $f_c$                    | -                  | 80        | -          | kHz           | $V_{CE} = 5\text{V}, I_C = 2\text{mA}, R_L = 100\Omega, -3\text{dB}$ |
| Floating capacitance                 | $C_{IO}$                 | -                  | 0.6       | 1.0        | pF            | $V_{IO} = 0, f = 1\text{MHz}$  |
| Rise time                            | $t_r$                    | -                  | 6         | 18         | $\mu\text{s}$ | $V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$              |
| Fall time                            | $t_f$                    | -                  | 8         | 18         | $\mu\text{s}$ |  |

\* Typical values at  $T_a = 25^\circ\text{C}$

Typical Electro-Optical Characteristics Curves

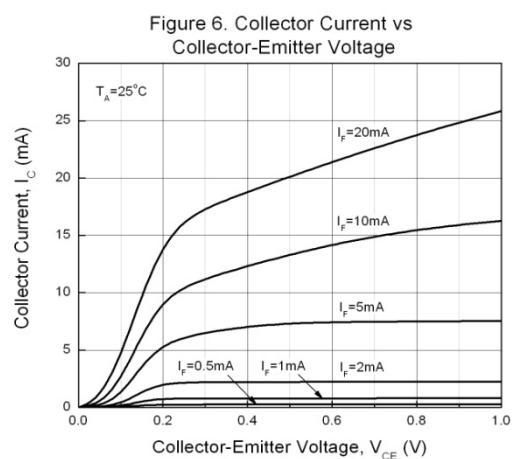
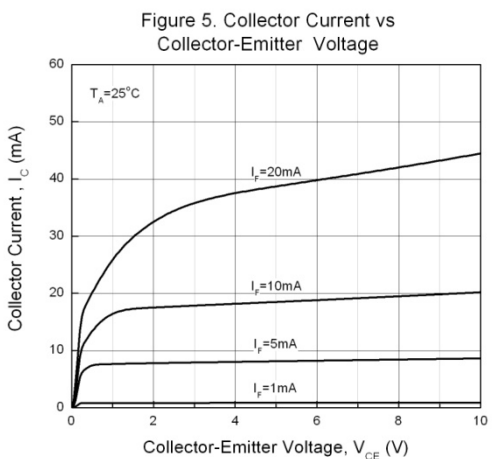
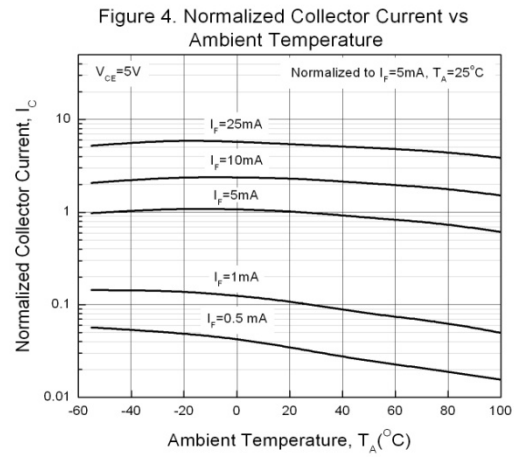
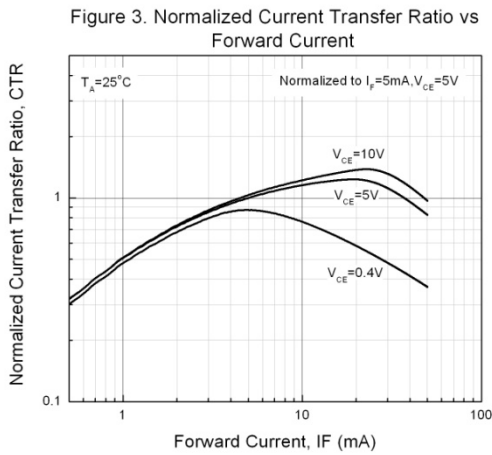
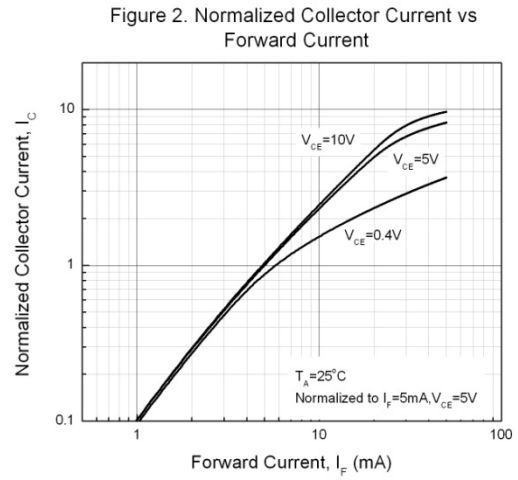
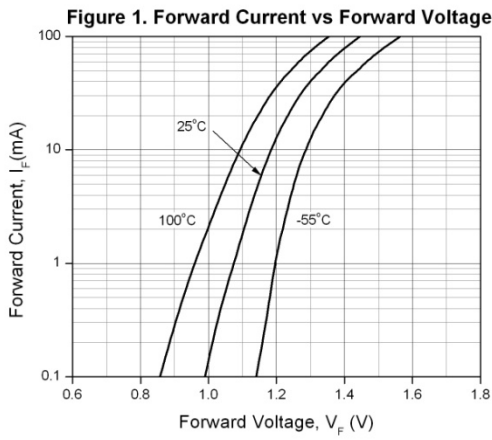


Figure 7. Collector Dark Current vs Ambient Temperature

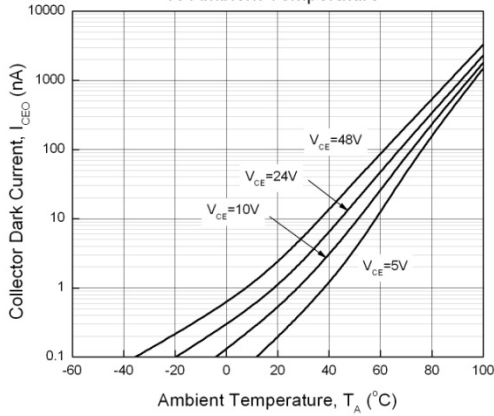


Figure 8. Switching Time vs Load Resistance

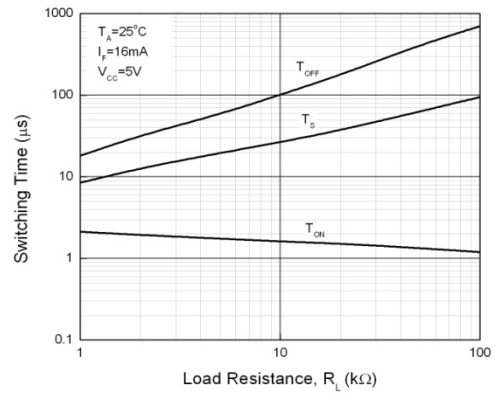


Figure 9. Collector-Emitter Saturation Voltage vs Ambient Temperature

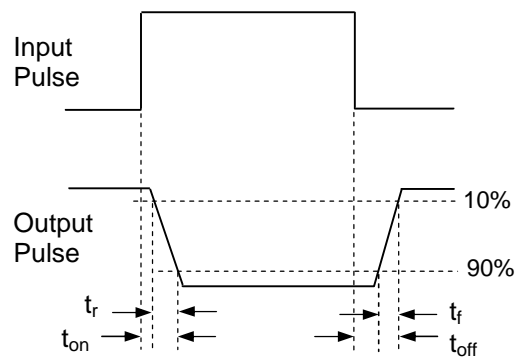
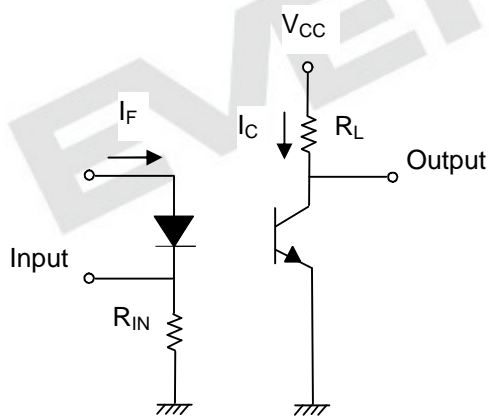
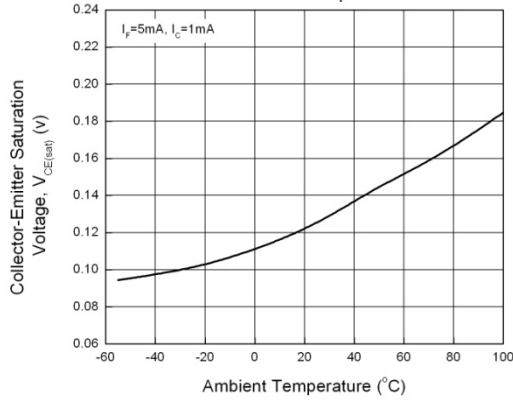


Figure 10. Switching Time Test Circuit & Waveforms

## Order Information

### Part Number

**EL354N(X)(Y)-VG**

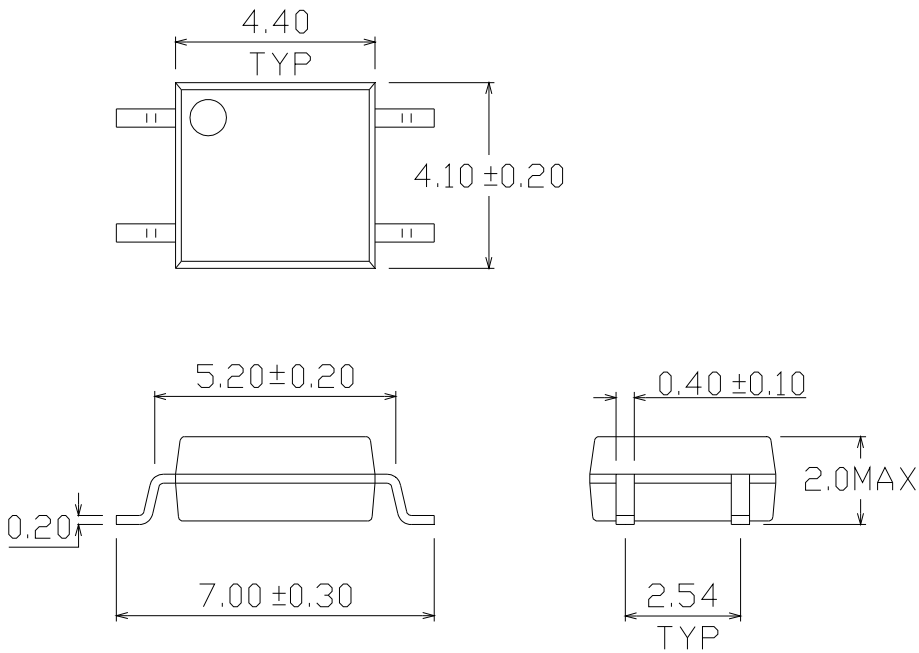
### Note

- X = CTR Rank option (A, or none)
- Y = Tape and reel option (TA, TB, or none).
- V = VDE (option)
- G = Halogens free

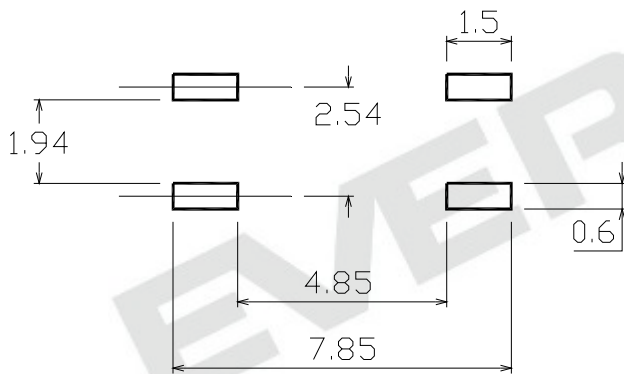
| Option | Description                 | Packing quantity    |
|--------|-----------------------------|---------------------|
| None   | Standard SMD option         | 100 units per tube  |
| -V     | Standard SMD option + VDE   | 100 units per tube  |
| (TA)   | TA Tape & reel option       | 3000 units per reel |
| (TB)   | TB Tape & reel option       | 3000 units per reel |
| (TA)-V | TA Tape & reel option + VDE | 3000 units per reel |
| (TB)-V | TB Tape & reel option + VDE | 3000 units per reel |

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Package Dimension (Dimensions in mm)



Recommended pad layout for surface mount leadform



### Device Marking



### Notes

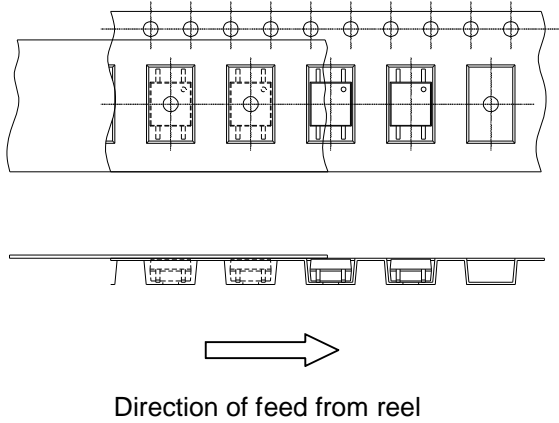
|      |                                 |
|------|---------------------------------|
| EL   | denotes Everlight               |
| 354N | denotes Device Number           |
| R    | denotes CTR Rank (A or none)    |
| Y    | denotes 1 digit Year code       |
| WW   | denotes 2 digit Week code       |
| V    | denotes VDE approved (optional) |

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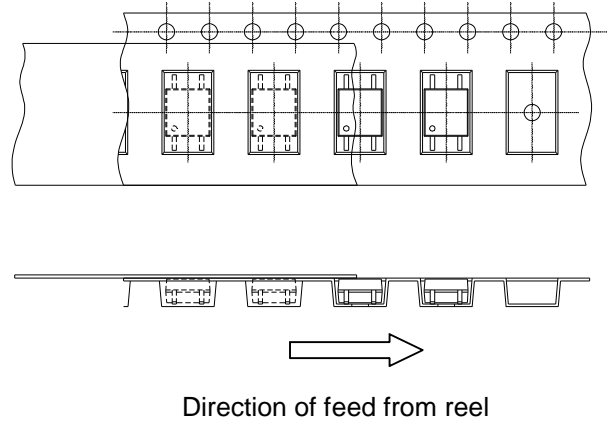


**Tape & Reel Packing Specifications**

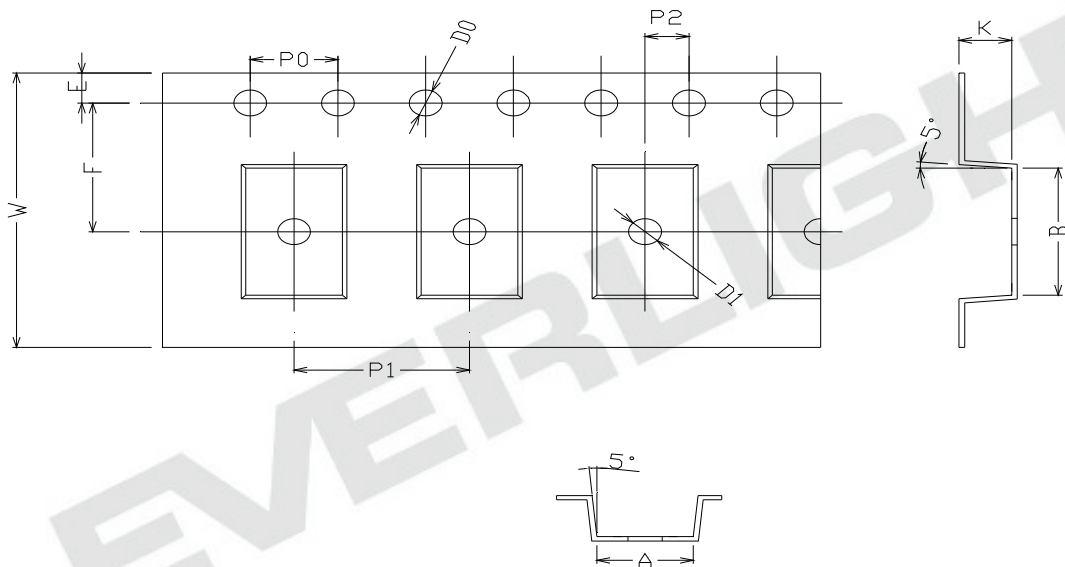
**Option TA**



**Option TB**



**Tape dimensions**

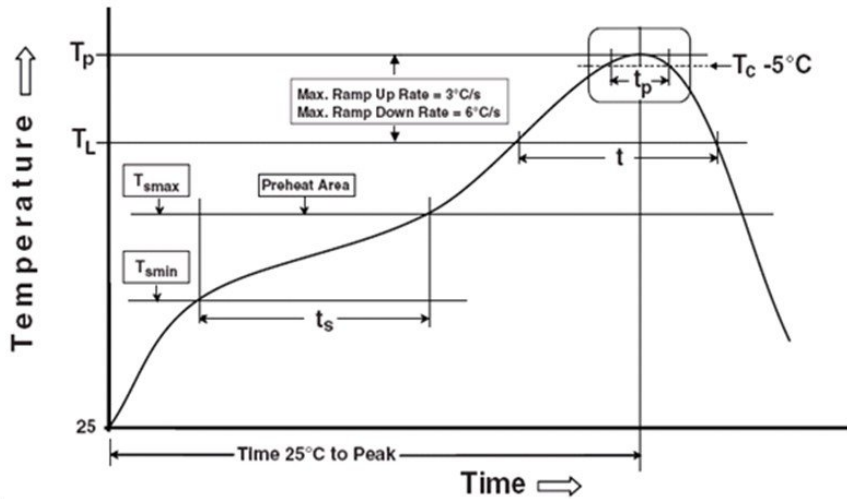


|                |            |           |              |             |            |            |
|----------------|------------|-----------|--------------|-------------|------------|------------|
| Dimension No.  | <b>A</b>   | <b>B</b>  | <b>Do</b>    | <b>D1</b>   | <b>E</b>   | <b>F</b>   |
| Dimension (mm) | 4.4 ± 0.1  | 7.6 ± 0.1 | 1.5 + 0.1/-0 | 1.5 ± 0.1   | 1.75 ± 0.1 | 7.5 ± 0.05 |
| Dimension No.  | <b>Po</b>  | <b>P1</b> | <b>P2</b>    | <b>t</b>    | <b>W</b>   | <b>K</b>   |
| Dimension (mm) | 4.0 ± 0.05 | 8.0 ± 0.1 | 2.0 ± 0.05   | 0.25 ± 0.03 | 16.0 ± 0.2 | 2.4 ± 0.1  |

**Precautions for Use**

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

**Preheat**

|  |                 |
|--|-----------------|
| Temperature min ( $T_{smin}$ )               | 150 °C          |
| Temperature max ( $T_{smax}$ )               | 200°C           |
| Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ )  | 60-120 seconds  |
| Average ramp-up rate ( $T_{smax}$ to $T_p$ ) | 3 °C/second max |

**Other**

|  |                  |
|--|------------------|
| Liquidus Temperature ( $T_L$ )                                       | 217 °C           |
| Time above Liquidus Temperature ( $t_L$ )                            | 60-100 sec       |
| Peak Temperature ( $T_p$ )   | 260°C            |
| Time within 5 °C of Actual Peak Temperature: $T_p - 5^\circ\text{C}$ | 30 s             |
| Ramp- Down Rate from Peak Temperature                                | 6°C /second max. |
| Time 25°C to peak temperature  | 8 minutes max.   |
| Reflow times   | 3 times          |

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2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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